

Common Cathode Fast Recovery Epitaxial Diode (FRED)

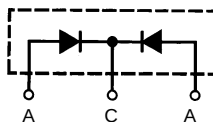
DSEK 30

$$I_{FAVM} = 2 \times 26 \text{ A}$$

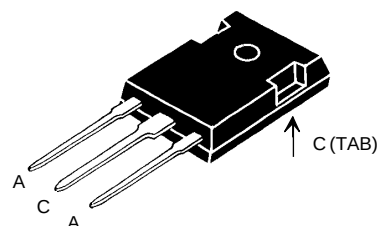
$$V_{RRM} = 1200 \text{ V}$$

$$t_{rr} = 40 \text{ ns}$$

V_{RSM}	V_{RRM}	Type
V	V	
1200	1200	DSEK 30-12A



TO-247 AD



A = Anode, C = Cathode, TAB = Cathode

Symbol	Test Conditions	Maximum Ratings	
I_{FRMS}	$T_{VJ} = T_{VJM}$	50	A
$I_{FAVM} \star$	$T_C = 85^\circ\text{C}$; rectangular, $d = 0.5$	26	A
I_{FRM}	$t_p < 10 \mu\text{s}$; rep. rating, pulse width limited by T_{VJM}	375	A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine	200	A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	210	A
	$T_{VJ} = 150^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine	185	A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	195	A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine	200	A^2s
	$t = 8.3 \text{ ms}$ (60 Hz), sine	180	A^2s
	$T_{VJ} = 150^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine	170	A^2s
	$t = 8.3 \text{ ms}$ (60 Hz), sine	160	A^2s
T_{VJ}		-40...+150	$^\circ\text{C}$
T_{VJM}		150	$^\circ\text{C}$
T_{stg}		-40...+150	$^\circ\text{C}$
P_{tot}	$T_C = 25^\circ\text{C}$	125	W
M_d	Mounting torque with screw M3	0.45-0.55/4-5	Nm/lb.in.
	Mounting torque with screw M3.5	0.45-0.55/4-5	Nm/lb.in.
Weight		6	g

Symbol	Test Conditions	Characteristic Values	
		typ.	max.
I_R	$T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$	750	μA
	$T_{VJ} = 25^\circ\text{C}$ $V_R = 0.8 \cdot V_{RRM}$	250	μA
	$T_{VJ} = 125^\circ\text{C}$ $V_R = 0.8 \cdot V_{RRM}$	7	mA
V_F	$I_F = 37 \text{ A}$; $T_{VJ} = 150^\circ\text{C}$	2.2	V
	$T_{VJ} = 25^\circ\text{C}$	2.55	V
V_{T0}	For power-loss calculations only	1.65	V
r_T	$T_{VJ} = T_{VJM}$	18.2	$\text{m}\Omega$
R_{thJC}		0.9	K/W
R_{thCK}		0.5	K/W
R_{thJA}		70	K/W
t_{rr}	$I_F = 1 \text{ A}$; $-di/dt = 100 \text{ A}/\mu\text{s}$; $V_R = 30 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$	40	ns
I_{RM}	$V_R = 540 \text{ V}$; $I_F = 30 \text{ A}$; $-di/dt = 240 \text{ A}/\mu\text{s}$	16	A
	$L \leq 0.05 \mu\text{H}$; $T_{VJ} = 100^\circ\text{C}$		

$\star I_{FAVM}$ rating includes reverse blocking losses at T_{VJM} , $V_R = 0.8 V_{RRM}$, duty cycle $d = 0.5$

Data according to DIN/IEC 747 and refer to a single diode unless otherwise stated.

IXYS reserves the right to change limits, test conditions and dimensions

Features

- International standard package JEDEC TO-247 AD
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low I_{RM} -values
- Soft recovery behavior
- Epoxy meets UL 94V-0 flammability classification

Applications

- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses
- Operating at lower temperature or space saving by reduced cooling

94538A

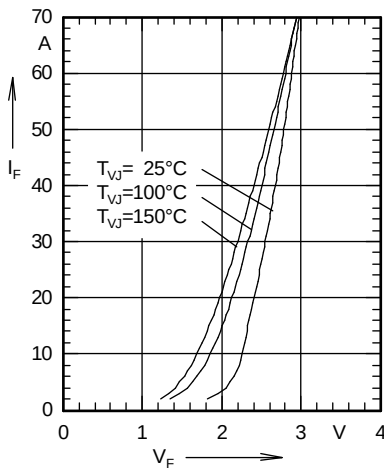


Fig. 1 Forward current versus voltage drop.

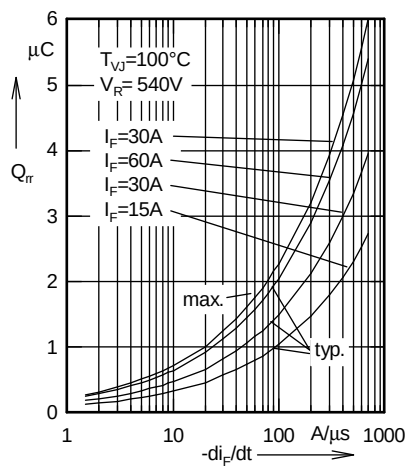


Fig. 2 Recovery charge versus $-di_F/dt$.

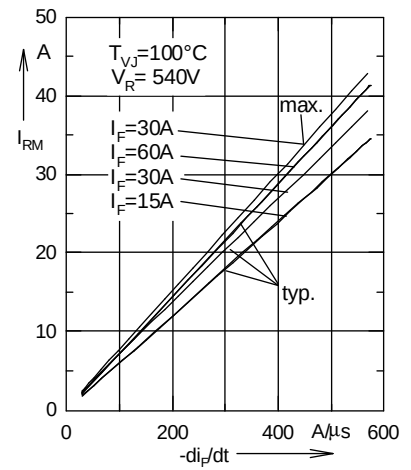


Fig. 3 Peak reverse current versus $-di_F/dt$.

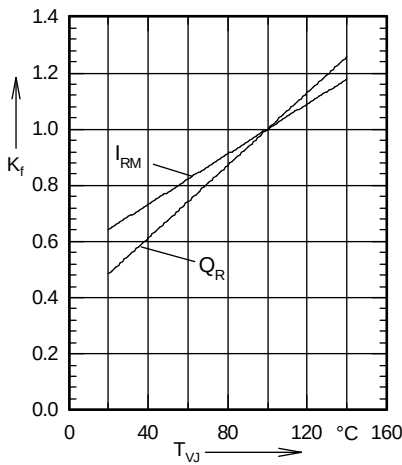


Fig. 4 Dynamic parameters versus junction temperature.

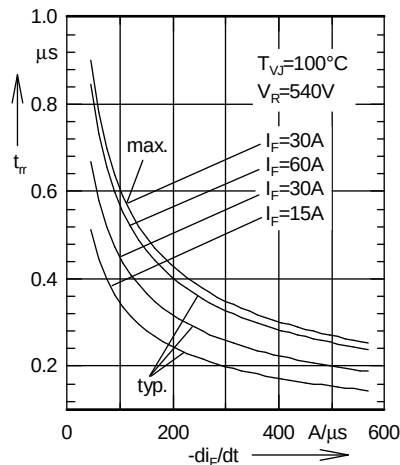


Fig. 5 Recovery time versus $-di_F/dt$.

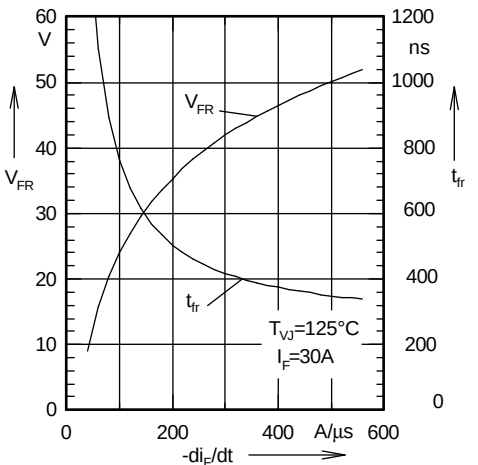


Fig. 6 Peak forward voltage versus $-di_F/dt$.

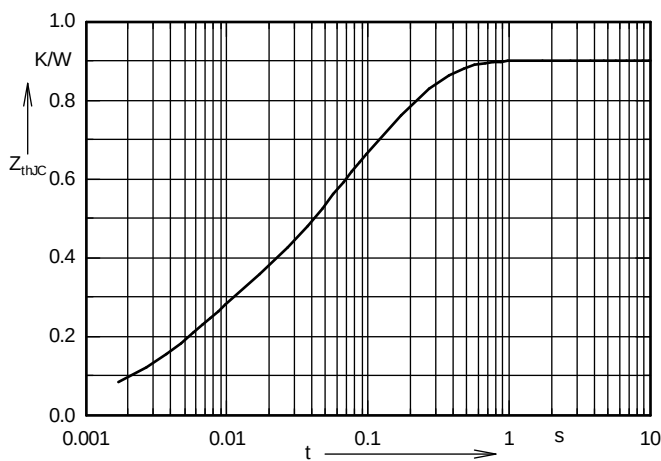
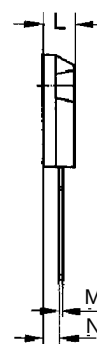
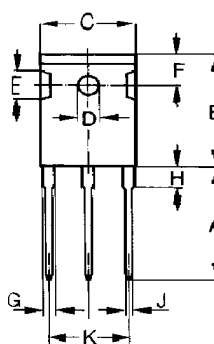


Fig. 7 Transient thermal impedance junction to case

Dimensions



Dim.	Millimeter	Min.	Max.	Inches	Min.	Max.
A	19.81	20.32		0.780	0.800	
B	20.80	21.46		0.819	0.845	
C	15.75	16.26		0.610	0.640	
D	3.55	3.65		0.140	0.144	
E	4.32	5.49		0.170	0.216	
F	5.4	6.2		0.212	0.244	
G	1.65	2.13		0.065	0.084	
H	-	4.5		-	0.177	
J	1.0	1.4		0.040	0.055	
K	10.8	11.0		0.426	0.433	
L	4.7	5.3		0.185	0.209	
M	0.4	0.8		0.016	0.031	
N	1.5	2.49		0.087	0.102	